



Product Features

- 1.9 GHz Power Amp Module
- 33.5 dB Gain
- + 34 dBm Linear Output Power
- Single +10V Supply
- No negative voltage required
- Low cost metal package
- MTTF > 100 Years

Applications

- PAS Base Stations
- Repeaters

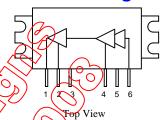
Product Description

The ECM168 is a high performance PHS Amplifier Module offering excellent linearity. The internally matched multi-stage amplifier has 33.5 dB gain while achieving +34 dBm linear output power to meet PHS's stringent ACLR requirements.

The ECM168 uses a high reliability InGaP/GaAs HBT process technology and does not require any external matching components. The module has an added benefit by not require any negative biasing voltages; an internal active bias allows the ECM168 to maintain high linearity over temperature and operate directly off a single +10V supply. A low-cost metal housing allows the device to have a low thermal resistance and achieves over 100 years MTTF. All devices are 100% RF and DC tested.

The ECM168 is targeted for use as a driver amplifier in wireless infrastructure where high linearity and high power is required. This combination makes the device an excellent candidate for next generation PAS base stations.

Functional Diagram



Rin No.	Function			
	RF Output			
$\sqrt{2}$	Vcc2			
3	No Connect			
4	Vcc1			
5	No Connect			
6	RF Input			
Case	Ground			

Specifications (1)

Parameter	Symbol	Units(Min /		May	Test Conditions
Frequency	f	MHz	1880 – 1920	<i>08</i>)/p	IVIAA	
Power Gain	Ga	dB	32.2	33.5	34.8	Pout = $+34$ dBm, Vd = 10 V
A CL D (COOL LL)	D- J:1		(90)	-67	-64	Pout = $+34 \text{ dBm}$, Vd = 10V , See note 2
ACLR (±600kHz)	Padj1	dBe		-69		Pout = $+33.5$ dBm, Vd = 10 V
ACLR (±900kHz)	Padj2	gBc		-74	-70	Pout = $+34$ dBm, Vd = 10 V
Input VSWR			~	1.5		Pout = $+34$ dBm, Vd = 10 V
2 nd Order Harmonic Distortion	2fo (%)	dBc /		-50		Pout = $+34$ dBm, Vd = 10 V
3 rd Order Harmonic Distortion	3fo	dBc		-50		Pout = $+34$ dBm, Vd = 10 V
Supply Voltage	Vccl Vec2	(0)		+10		
Operating Current	Toc	mA	1000	1100	1300	Pout = $+34$ dBm, Vd = 10 V

Test conditions unless otherwise noted: 25 °C, Supply Voltage = +10 V (Outpu) Power = +34 dBm, RF signal modulation is per PHS RCR-28.

Absolute Maximum Rating

Parameter	Rating
Storage Temperature	-55 to +150 °C
Input RF Power	+10 dBm
Supply Voltage	+10 V

Operation of this device above any of these parameters may cause permanent damage

Ordering Information

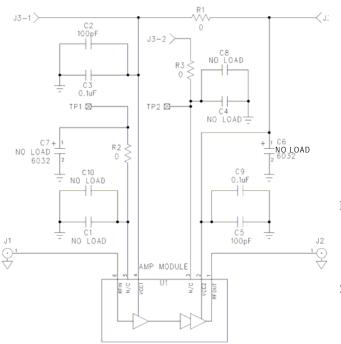
Part No.	Description
ECM168	PHS +34 dBm 10V Module
ECM168-PCB	Fully Assembled Evaluation Board

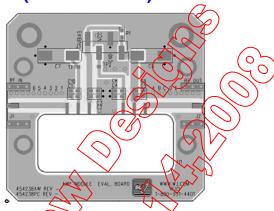
ACLR specification of -65 dBc at +34 dBm output power. The actual test limits performed by WJ correspond





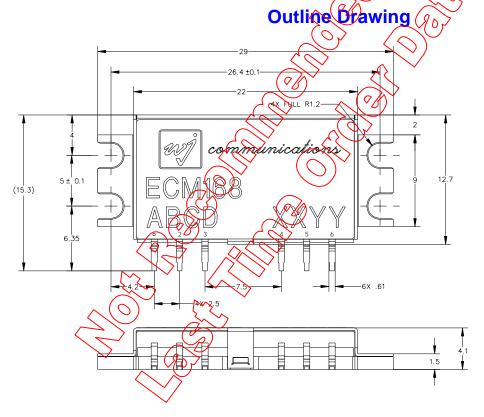
Recommended Application Circuit (ECM168-PCB)



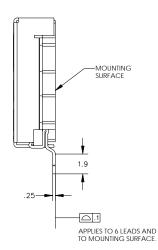


Notes:

- Please note that for reliable operation, the evaluation board will have to be mounted to a much larger heat sink during operation and in laboratory environments to dissipate the power consumed by the device. The use of a convection fan is also recommended in laboratory environments.
- 2. The area around the module underneath the PCB should not contain any soldermask in order to maintain good RF grounding.



PIN ASSIGNMENT (1) RF Out, (2) Vcc, (3) N/C (4) Vcc, (5) N/C, (6) RF In Case: GND



DIMENIONS IN MM





Performance Graphs

